

FJH1100

Ultra Low Leakage Diode

General Description

An Ultra low leakage diode in the DO-35 package. The forward voltage is typically greater than 0.5 volts at 1.0 micro-ampere.

This product is light sensitive, any damage to the body coating will affect the reverse leakage when exposed to light.



DO-35

Color Band Denotes Cathode

Absolute Maximum Ratings * $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
W_{IV}	Working Inverse Voltage	15	V
I_F	DC Forward Current (I_F)	150	mA
P_D	Total Power Dissipation at $T_A = 25^\circ\text{C}$	250	mW
	Linear Derating Factor from $T_A = 25^\circ\text{C}$	1.67	mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient	300	$^\circ\text{C}/\text{W}$
T_{STG}	Storage Temperature	-55 to +200	$^\circ\text{C}$
T_J	Operating Junction Temperature	175	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ.	Max.	Units
B_V	Breakdown Voltage	$I_R = 5.0\mu\text{A}$	30			V
I_R	Reverse Leakage	$V_R = 5.0\text{V}$ $V_R = 15\text{V}$			3.0 10	pA pA
V_F	Forward Voltage	$I_F = 1.0\mu\text{A}$ $I_F = 10\mu\text{A}$ $I_F = 100\mu\text{A}$ $I_F = 1.0\text{mA}$ $I_F = 10\text{mA}$ $I_F = 50\text{mA}$ $I_F = 100\text{mA}$		530 605 685 780 895 995 1.07	1050	mV mV mV mV mV mV V
C_T	Diode Capacitance	$V_R = 0\text{V}$, $f = 1.0\text{MHz}$			2.0	pF

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Rev. I15